

# 7705(A), 7706

The NCV7705/NCV7706 is a powerful Driver-IC for automotive body control systems. The IC is designed to control several loads in the front door of a vehicle. The monolithic IC is able to control mirror functions like mirror positioning, heating and folding. In addition, NCV7706 includes the electro-chromic mirror feature. The device features four high-side outputs to drive LEDs or incandescent bulbs (up to 5/10 W). To allow maximum flexibility, all lighting outputs can be PWM controlled thru PWM inputs (external signal source) or by an internal programmable PWM generator unit. The NCV7705/NCV7706 is controlled thru a 24 bit SPI interface with in-frame response.

## Features

- Operating Range from 5.5 V to 28 V
- Four High-Side and Four Low-Side Drivers Connected as Half-Bridges
  - ◆ 2x Half-bridges  $I_{load} = 0.75\text{ A}$ ;  $R_{DS(on)} = 1.6\ \Omega @ 25^\circ\text{C}$
  - ◆ 2x Half-Bridges  $I_{load} = 3\text{ A}$ ;  $R_{DS(on)} = 300\text{ m}\Omega @ 25^\circ\text{C}$
- Four High-Side Lamp Drivers
  - ◆ 2x LED;  $I_{load} = 0.3\text{ A}$ ;  $R_{DS(on)} = 1.4\ \Omega @ 25^\circ\text{C}$
  - ◆ 1x 10 W; Configurable as LED Driver;  $I_{load} = 2.5\text{ A}$ ;  $R_{DS(on)} = 300\text{ m}\Omega @ 25^\circ\text{C}$
  - ◆ 1x 5 W; Configurable as LED Driver;  $I_{load} = 1.25\text{ A}$ ;  $R_{DS(on)} = 600\text{ m}\Omega @ 25^\circ\text{C}$
- 1x High-Side Driver for Mirror Heating;  $I_{load} = 6\text{ A}$ ;  $R_{DS(on)} = 100\text{ m}\Omega @ 25^\circ\text{C}$
- Electro Chromic Mirror Control (NCV7706 Only)
  - ◆ 1x 6-Bit Selectable Output Voltage Controller
  - ◆ 1x LS for EC Control;  $I_{load} = 0.75\text{ A}$ ;  $R_{DS(on)} = 1.6\ \Omega @ 25^\circ\text{C}$
- Independent PWM Functionality for All Outputs
- Integrated Programmable PWM Generator Unit for All Lamp Driver Outputs
  - ◆ 7-bit / 10-bit Selectable Duty-cycle Setting Precision
- Programmable Soft-start Function to Drive Loads with Higher Inrush Currents as Current Limitation Value
- Multiplex Current Sense Analog Output for Advanced Load Monitoring
- Very Low Current Consumption in Standby Mode
- Charge Pump Output to Control an External Reverse Polarity Protection MOSFET
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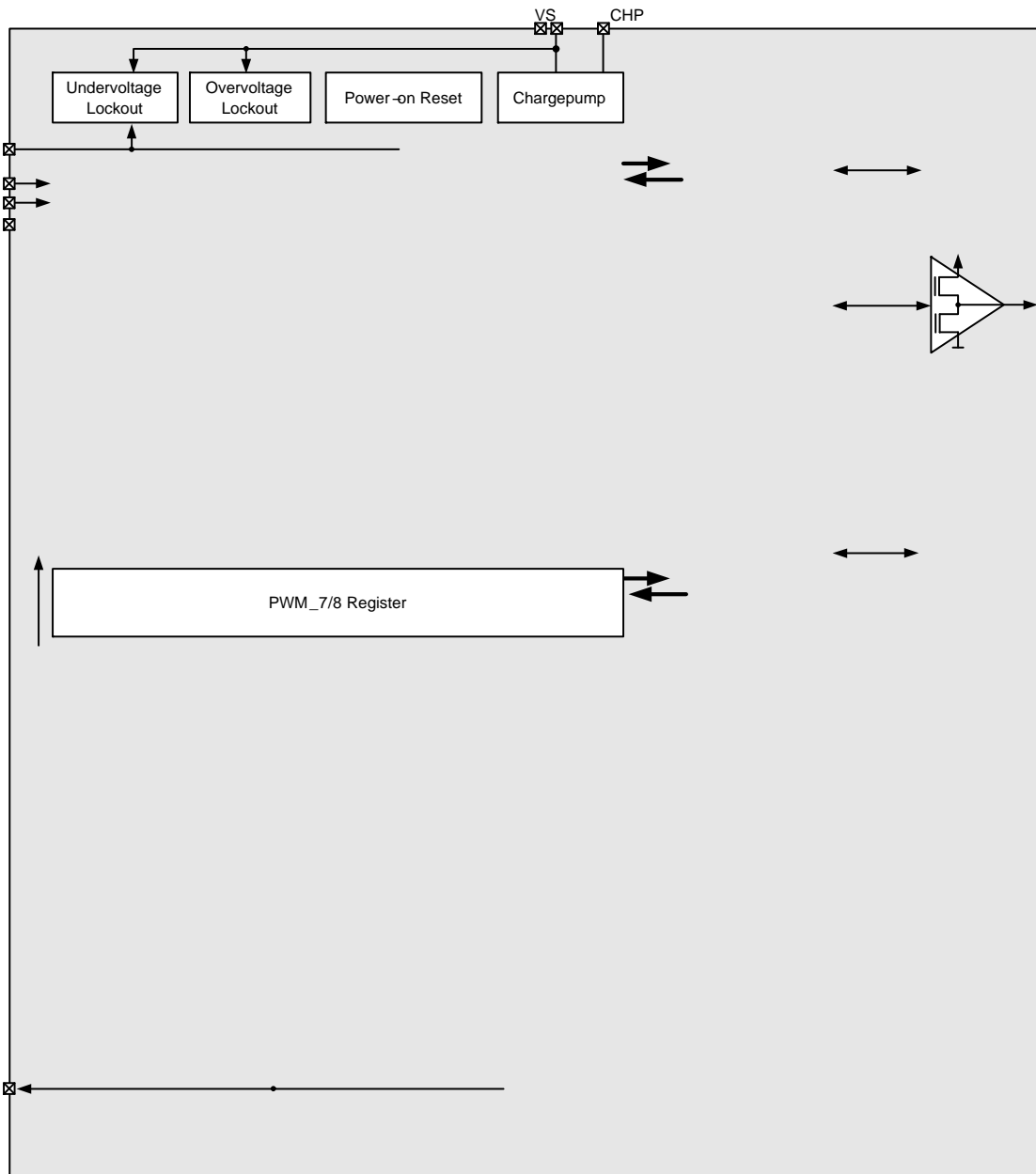


Figure 1. Block Diagram

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## PIN FUNCTION DESCRIPTION

Pin No.	Pin Name	Pin Type	Description
1	GND	Ground	

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## ABSOLUTE MAXIMUM RATINGS

Symbol	Rating	Min	Max	Unit
Vs	Power supply voltage - Continuous supply voltage - Transient supply voltage (t < 500 ms, "clamped load dump")	-0.3 -0.3	28 40	

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## ELECTRICAL CHARACTERISTICS

4.5 V < V<sub>CC</sub> < 5.25 V, 8 V < V<sub>s</sub> < 18 V, -40°C < T<sub>J</sub> < 150°C; unless otherwise noted.

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
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### SUPPLY

V <sub>s</sub>	Supply voltage	Functional (see V <sub>UV_VS</sub> / V <sub>OV_VS</sub> ) Parameter specification	5.5 8		28 18	V
I <sub>s(standby)</sub>	Supply Current (V <sub>S</sub> ), Standby mode	Standby mode, V <sub>S</sub> = 16 V, 0 V ≤ V <sub>CC</sub> ≤ 5.25 V, CSB = V <sub>CC</sub> , OUTx/ECx = floating, SI = SCLK = 0 V, T <sub>J</sub> < 85°C (T <sub>J</sub> = 150°C)		3.5 (9)	12 (25)	μA
I <sub>s(active)</sub>	Supply current (V <sub>S</sub> ), Active mode	Active mode, V <sub>S</sub> = 16 V, OUTx/ECx = floating		8	20	mA
I <sub>CC(standby)</sub>	Supply Current (V <sub>CC</sub> ), Standby mode	Standby mode, V <sub>CC</sub> = 5.25 V, SI = SCLK = 0 V, T <sub>J</sub> < 85°C (T <sub>J</sub> = 150°C)		4.5 (15)	6 (50)	μA

I

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## ELECTRICAL CHARACTERISTICS (continued)

4.5 V < V<sub>CC</sub> < 5.25 V, 8 V < V<sub>s</sub> < 18 V, -40°C < T<sub>J</sub> < 150°C; unless otherwise noted.

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
<b>MIRROR COMMON OUTPUT (X/Y, FOLD) OUT1, OUT4</b>						
Ron_out1,4	On-resistance HS or LS	T <sub>J</sub> = 25°C, I <sub>out1,4</sub> = ±1.5 A		0.3		Ω
		T <sub>J</sub> = 125°C, I <sub>out1,4</sub> = ±1.5 A			0.6	
Ioc1,4_hs	Overcurrent threshold HS	T <sub>J</sub> < 25°C T <sub>J</sub> ≥ 25°C	-5.5 -5		-3	A
Ioc1,4_ls	Overcurrent threshold LS	T <sub>J</sub> < 25°C T <sub>J</sub> ≥ 25°C	3		5.5 5	A
Vlim1,4	V <sub>ds</sub> voltage limitation HS or LS		2		3	V
Iuld1,4_hs	Underload detection threshold HS		-80		-5	mA
Iuld1,4_ls	Underload detection threshold LS		5		80	mA
td_HS1,4(on)	Output delay time, HS Driver on	Time from CSB going high to V(OUT1,4) = 0.1·V <sub>s</sub> / 0.9·V <sub>s</sub> (on/off)		2.5	12	μs
td_HS1,4(off)	Output delay time, HS Driver off			3	12	μs
td_LS1,4(on)	Output delay time, LS Driver on	Time from CSB going low to V(OUT1,4) = 0.9·V <sub>s</sub> / 0.1·V <sub>s</sub> (on/off)		1	12	μs
td_LS1,4(off)	Output delay time, LS Driver off			1.5	12	μs
tdLH1,4	Cross conduction protection time, low-to-high transition including LS slew-rate			0.5	22	μs
tdHL1,4	Cross conduction protection time, high-to-low transition including HS slew-rate			5.5	22	μs
Ileak_act_hs1,4	Output HS leakage current, Active mode	V(OUT1,4) = 0 V	-40	-16		μA
Ileak_act_ls1,4	Output pull-down current, Active mode	V(OUT1,4) = V <sub>s</sub>		105	185	μA
Ileak_stdbys1,4	Output HS leakage current, Standby mode	V(OUT1,4) = 0 V	-5			μA
Ileak_stdbys_ls1,4	Output pull-down current, Standby mode	V(OUT1,4) = V <sub>s</sub> , T <sub>J</sub> ≥ 25°C V(OUT1,4) = V <sub>s</sub> , T <sub>J</sub> < 25°C		80	120 175	μA
td_uld1,4	Underload blanking delay		430		610	μs
tdb_old1,4	Overload shutdown blanking delay	Timer started after output activation	16		25	μs
td_old1,4	Overload shutdown filter time	Timer started after blanking delay				

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## ELECTRICAL CHARACTERISTICS (continued)

4.5 V < V<sub>CC</sub> < 5.25 V, 8 V < V<sub>s</sub> < 18 V, -40°C < T<sub>J</sub> < 150°C; unless otherwise noted.

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
<b>MIRROR X/Y POSITIONING OUTPUTS OUT2, OUT3</b>						
Ron_out2,3	On-resistance HS or LS	T <sub>J</sub> = 25°C, I <sub>out2,3</sub> = ±0.5 A		1.6		Ω
		T <sub>J</sub> = 125°C, I <sub>out2,3</sub> = ±0.5 A			3	Ω
Ioc2,3_hs	Overcurrent threshold HS	T <sub>J</sub> < 25°C T <sub>J</sub> ≥ 25°C	-1.35 -1.25		-0.75	A
Ioc2,3_ls	Overcurrent threshold LS	T <sub>J</sub> < 25°C T <sub>J</sub> ≥ 25°C	0.75		1.35 1.25	A
Vlim2,3	V <sub>ds</sub> voltage limitation HS or LS		2		3	V
Iuld2,3_hs	Underload detection threshold HS		-32	-20	-10	mA
Iuld2,3_ls	Underload detection threshold LS		10	20	32	mA
td_HS2,3(on)	Output delay time, HS Driver on	Time from CSB going high to V(OUT2,3) = 0.1·V <sub>s</sub> / 0.9·V <sub>s</sub> (on/off)		2.5	6	μs
td_HS2,3(off)	Output delay time, HS Driver off			3	6	μs
td_LS2,3(on)	Output delay time, LS Driver on	Time from CSB going low to V(OUT2,3) = 0.9·V <sub>s</sub> / 0.1·V <sub>s</sub> (on/off)		1	6	μs
td_LS2,3(off)	Output delay time, LS Driver off			1	6	μs
tdLH2,3	Cross conduction protection time, low-to-high transition including LS slew-rate			0.5	22	μs
tdHL2,3	Cross conduction protection time, high-to-low transition including HS slew-rate			5.5	22	μs
Ileak_act_hs2,3	Output HS leakage current, Active mode	V(OUT2,3) = 0 V	-40	-16		μA
Ileak_act_ls2,3	Output pull-down current, Active mode	V(OUT2,3) = V <sub>s</sub>		105	185	μA
Ileak_stdby_hs2,3	Output HS leakage current, Standby mode	V(OUT2,3) = 0 V	-5			μA
Ileak_stdby_ls2,3	Output pull-down current, Standby mode	V(OUT2,3) = V <sub>s</sub> , T <sub>J</sub> ≥ 25°C V(OUT2,3) = V <sub>s</sub> , T <sub>J</sub> < 25°C		80	120 175	μA μA
td_uld2,3	Underload blanking delay		430		610	μs
tdb_ol2,3	Overload shutdown blanking delay	Timer started after output activation	16		25	μs
td_ol2,3	Overload shutdown filter time	Timer started after blanking delay elapsed	16		50	μs
frec2,3L	Recovery frequency, slow recovery mode	CONTROL_3.OCRf = 0	1		4	kHz
frec2,3H	Recovery frequency, fast recovery mode	CONTROL_3.OCRf = 1	2		6	kHz
dVout2,3	Slew rate of HS driver	V <sub>s</sub> = 13.5 V, R <sub>load</sub> = 64 Ω to GND	1.3	2.3	3.3	V/μs



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## ELECTRICAL CHARACTERISTICS (continued)

4.5 V < V<sub>CC</sub> < 5.25 V, 8 V < V<sub>s</sub> < 18 V, -40°C < T<sub>J</sub> < 150°C; unless otherwise noted.

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
<b>BULB / LED DRIVER OUTPUT OUT5</b>						
Ron_out5_ICB	On-resistance to supply, HS switch, Bulb mode	T <sub>J</sub> = 25°C, I <sub>out5</sub> = -1 A		0.3		Ω
		T <sub>J</sub> = 125°C, I <sub>out5</sub> = -1 A			0.6	
Ron_out5_LED	On-resistance to supply, HS switch, LED mode	T <sub>J</sub> = 25°C, I <sub>out5</sub> = -0.2 A		1.4		Ω
		T <sub>J</sub> = 125°C, I <sub>out5</sub> = -0.2 A			3	
Ilim5_ICB	Output current limitation to GND, Bulb mode	T <sub>J</sub> < 25°C T <sub>J</sub> ≥ 25°C	-3.9 -3.7		-2.5	A
Ilim5_LED	Overcurrent threshold, LED mode		-1.1		-0.5	A
Iuld5_ICB	Underload detection threshold, Bulb mode		-65		-5	mA
Iuld5_LED	Underload detection threshold, LED mode		-15		-5	mA
td_OUT5_ICB(on)	Output delay time, Driver on, Bulb mode	Time from CSB going high to V(OUT5) = 0.1·Vs / 0.9·Vs (on/off); Rload = 16 Ω		15	48	μs
td_OUT5_ICB(off)	Output delay time, Driver off, Bulb mode			21	48	
td_OUT5_LED(on)	Output delay time, Driver on, LED mode	Time from CSB going high to V(OUT5) = 0.1·Vs / 0.9·Vs (on/off); Rload = 64 Ω		15	48	μs
td_OUT5_LED(off)	Output delay time, Driver off, LED mode			21	48	

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## ELECTRICAL CHARACTERISTICS (continued)

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Symbol

Typ

Max

Unit



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### ELECTRICAL CHARACTERISTICS (continued)

4.5 V < V<sub>CC</sub> < 5.25 V, 8 V < V<sub>s</sub> < 18 V, -40°C < T<sub>J</sub> < 150°C; unless otherwise noted.

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
<b>ELECTROCHROMIC MIRROR CONTROL (ECFB, ECON) (NCV7706 ONLY)</b>						
Ron_ecfb	On-resistance to GND, LS switch	T <sub>J</sub> = 25°C, I <sub>ecfb</sub> = 0.5 A		1.6		Ω
		T <sub>J</sub> = 125°C, I <sub>ecfb</sub> = 0.5 A			3	Ω
Ilim_ecfb_src	Output current limitation to GND	V <sub>s</sub> = 13.5 V, V <sub>CC</sub> = 5 V	0.75		1.25	A
Vlim_ecfb	V <sub>ds</sub> voltage limitation	Output enabled	2		3	V
Iuld_ecfb	Underload detection threshold	V <sub>s</sub> = 13.5 V, V <sub>CC</sub> = 5 V	10	20	35	mA
td_ecfb(on)	Output delay time, LS Driver on	V <sub>s</sub> = 13.5 V, V <sub>CC</sub> = 5 V, R <sub>load</sub> = 64 Ω, V(ECFB) = 0.9·V <sub>S</sub> / 0.1·V <sub>S</sub> (on /off)		1	12	μs
td_ecfb(off)	Output delay time, LS Driver off			2	12	
Ileak_ecfb_stdby	Output leakage current, LS off	V <sub>ecfb</sub> = V <sub>s</sub> , Standby mode	-15		15	μA
Ileak_ecfb_act		V <sub>ecfb</sub> = V <sub>s</sub> , Active mode	-10		10	μA
td_uld_ecfb	Underload blanking delay		430		610	μs
tdb_old_ecfb	Overload shutdown blanking delay	Timer started after output activation	30		48	μs
td_old_ecfb	Overload shutdown filter time	Timer started after blanking delay elapsed	16		50	μs
dV <sub>ecfb</sub> /dt(on/off)	Slew rate of ECFB, LS switch	V <sub>s</sub> = 13.5 V, V <sub>CC</sub> = 5 V, R <sub>load</sub> = 64 Ω		5		V/μs
Vctrl_max	Maximum EC control voltage	CONTROL_2.FSR = 1	1.4		1.6	V
		CONTROL_2.FSR = 0	1.12		1.28	V
DNL	Differential non linearity	1 LSB = 23.8 mV	-1			

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## ELECTRICAL CHARACTERISTICS (continued)

4.5 V < V<sub>CC</sub> < 5.25 V, 8 V < V<sub>s</sub> < 18 V, -40°C < T<sub>J</sub> < 150°C; unless otherwise noted.

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
<b>CURRENT SENSE MONITOR OUTPUT ISOUT/PWM2</b>						
Vis	Current Sense output functional voltage range	V <sub>CC</sub> = 5 V, V <sub>s</sub> = 8–20 V	0		V <sub>CC</sub> – 0.5	V
Kis	Current Sense output ratio OUT1/4	K = I <sub>out</sub> / I <sub>is</sub> , 0 V ≤ Vis ≤ 4.5 V, V <sub>CC</sub> = 5 V		12000		
	Current Sense output ratio OUT9 and 5 (low on–resistance bulb mode)			10000		
	Current Sense output ratio OUT6 (low on–resistance bulb mode)			5000		
	Current Sense output ratio OUT7/8 and 5/6 (high on–resistance LED mode)			2000		
I <sub>is,acc</sub> (Notes 6 and 7)	Current Sense output accuracy OUT1/4	0.3 V ≤ Vis ≤ 4.5 V, V <sub>CC</sub> = 5 V I <sub>out1/4</sub> = 0.5–2.9 A	-12.5% – 1% FS		12.5% + 1% FS	
	Current Sense output accuracy OUT5/6 (low on–resistance bulb mode)	0.3 V ≤ Vis ≤ 4.5 V, V <sub>CC</sub> = 5 V I <sub>out5</sub> = 0.5–1.3 A, I <sub>out6</sub> = 0.25–0.65 A	-14% – 1% FS		14% + 1% FS	
	Current Sense output accuracy OUT5/6 (high on–resistance LED mode)	0.3 V ≤ Vis ≤ 4.5 V, V <sub>CC</sub> = 5 V I <sub>out5,6</sub> = 0.1–0.3 A	-14% – 1% FS		14% + 1% FS	
	Current Sense output accuracy OUT7/8	0.3 V ≤ Vis ≤ 4.5 V, V <sub>CC</sub> = 5 V	-8% – 1.5% FS		8% + 1.5% FS	
	Current Sense output accuracy OUT9	0.3 V ≤ Vis ≤ 4.5 V, V <sub>CC</sub> = 5 V I <sub>out9</sub> = 0.5–5.9 A	-10% – 1.5% FS		10% + 1.5% FS	
t <sub>is_blank</sub>	Current Sense blanking time	Blanking time after current sense selection or driver activation	50		65	μs
t <sub>is</sub>	Current Sense settling time	0 V to FSR (full scale range)		230	265	μs

6. Current sense output accuracy = I<sub>sout</sub> – I<sub>sout\_ideal</sub> relative to I<sub>sout\_ideal</sub>

7. FS (Full scale) = I<sub>outmax</sub>/K<sub>is</sub>

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## ELECTRICAL CHARACTERISTICS (continued)

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Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
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### DIGITAL INPUTS CSB, SCLK, PWM1/2, SI

V <sub>inl</sub>	Input low level	V <sub>CC</sub> = 5 V				0.3·V
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## ELECTRICAL CHARACTERISTICS (continued)

4.5 V < V<sub>CC</sub> < 5.25 V, 8 V < V<sub>s</sub> < 18 V, -40°C < T<sub>J</sub> < 150°C; unless otherwise noted.

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
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### DIGITAL OUTPUT SO

V <sub>sol</sub>	Output low level	I <sub>so</sub> = 5 mA			0.2·V <sub>CC</sub>	V
V <sub>soh</sub>	Output high level	I <sub>so</sub> = -5 mA	0.8·V <sub>CC</sub>			V
I <sub>leak_so</sub>	Tristate leakage current	V <sub>csb</sub> = V <sub>CC</sub> ; 0 V < V <sub>so</sub> < V <sub>CC</sub>	-10		10	μ

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## ELECTRICAL CHARACTERISTICS (continued)

4.5 V < V<sub>CC</sub> < 5.25 V, 8 V < V<sub>s</sub> < 18 V, -40°C < T<sub>J</sub> < 150°C; unless otherwise noted.

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
<b>THERMAL PROTECTION</b>						
Tjtw_on	Temperature warning threshold	Junction temperature	140		160	°C
Tjtw_hys	Thermal warning hysteresis			5		°C
Tjtd_on	Thermal shutdown threshold, T <sub>J</sub> increasing	Junction temperature	160		180	°C
Tjtd_off	Thermal shutdown threshold, T <sub>J</sub> decreasing	Junction temperature	160			°C
Tjtd_hys	Thermal shutdown hysteresis			5		°C
Tjtdtw_delta	Temperature difference between warning and shutdown threshold			20		



## DETAILED OPERATING AND PIN DESCRIPTION

### General

The NCV7705/NCV7706 provides four half-bridge drivers, five independent high-side outputs and a programmable PWM control unit for free configuration. Strict adherence to integrated circuit die temperature is necessary, with a static maximum die temperature of 150°C. This may limit the number of drivers enabled at one time. Output drive control and fault reporting are handled via the SPI (Serial Peripheral Interface) port. A SPI-controlled mode control provides a low quiescent sleep current mode when the device is not being utilized. A pull down is provided on the SI and SCLK inputs to ensure they default to a low state in the event of a severed input signal. A pull-up is provided on the CSB input disabling SPI communication in the event of an open CSB input.

### Supply Concept

#### Power Supply Scheme – VS and VCC

The Vs power supply voltage is used to supply the half bridges and the high-side drivers. An all-internal chargepump is implemented to provide the gate-drive voltage for the n-channel type high-side transistors. The VCC voltage is used to supply the logic section of the IC, including the SPI interface.

Due to the independent logic supply voltage the control and status information will not be lost in case of a loss of Vs supply voltage. The device is designed to operate inside the specified parametric limits if the VCC supply voltage is within the specified voltage range (4.5 V to 5.25 V). Between the operational level and the VCC undervoltage threshold level (Vuv\_VCC) it is guaranteed that the device remains in a safe functional state without any inadvertent change to logic information.

#### Device / Module Ground Concept

The high-side output stages OUT5-9 are designed to handle DC output voltage conditions down to -0.3 V and allow for short negative transient currents due to parasitic line inductances. Therefore the application has to take care that these ratings are not violated under abnormal operating conditions (module loss of GND, ground shift if load connected to external GND) by either implementing external bypass diodes connected to GND or a direct connection between load-GND and module-GND. Since these output stages are designed to drive resistive loads,





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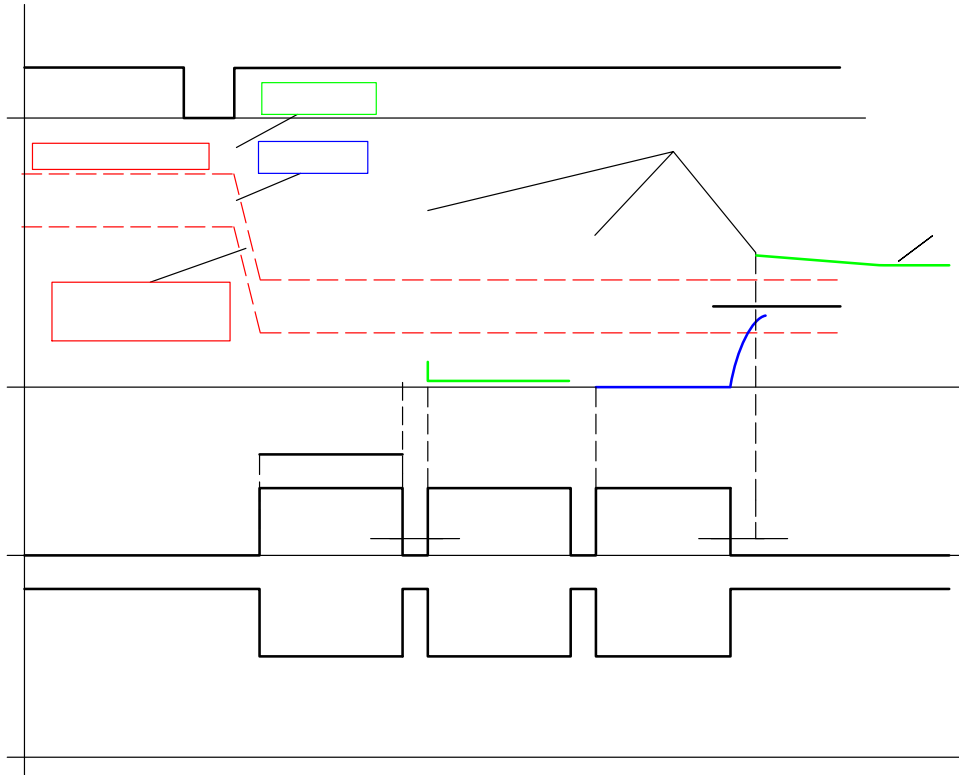


Figure 6. PWM Discharge Mode for ECFB

## Diagnostic Functions

All diagnostic functions (overcurrent, underload, power supply monitoring, thermal warning and thermal shutdown) are internally filtered. The failure condition has to be valid for the minimum specified filtering time ( $t_{d\_old}$ ,  $t_{d\_uld}$ ,  $t_{d\_uvov}$  and  $t_{d\_tx}$ ) before the corresponding status bit in the status register is set. The filter function is used to improve the noise immunity of the device. The undercurrent and temperature warning functions are intended for information purpose and do not affect the state of the output drivers. An overcurrent condition disables the corresponding output driver while a thermal shutdown event disables all outputs into high impedance state. Depending on the setting of the overcurrent recovery bits in the input register, the driver can either perform an auto-retry or remain latched off until the microcontroller clears the corresponding status bits. Overtemperature shutdown is latch-off only, without auto-retry functionality.

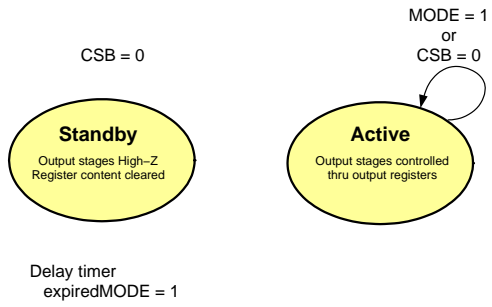
## Overvoltage / Undervoltage Shutdown

If the supply voltage  $V_s$  rises above the switch off voltage  $V_{ov\_vs(off)}$  or falls below  $V_{uv\_vs(off)}$ , all output transistors are switched to high-impedance state and the global status bit UOV\_OC (multi information) is set. The status flag STATUS\_2.VSOV, resp. STATUS\_2.VSUV is set, too, to log the over-/under-voltage event. The bit CONTROL\_3.OVUVR can be used to determine the recovery behavior once the  $V_s$  supply voltage gets back into the specified nominal operating range. OVUVR = 0 enables auto-recovery, with OVUVR = 1 the output stages remain in high impedance condition until the status flags have been cleared. Once set, STATUS2.VSOV / VSUV can only be reset by a read&clear access to the status register STATUS\_2.

## Thermal Warning and Overtemperature Shutdown

The device provides a dual-stage overtemperature protection. If the junction temperature rises above  $T_{jtw\_on}$ , a temperature warning flag (TW) is set in the Global Status Byte and can be read via SPI. The control software can then react onto this overload condition by a controlled disable of individual outputs. If however the junction temperature

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### 24-bit SPI Interface

Both 24-bit input and output data are MSB first. Each SPI-input frame consists of a command byte followed by two data bytes. The data returned on SO within the same frame always starts with the global status byte. It provides general status information about the device. It is then followed by 2 data bytes (in-frame rF0ata

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**Table 4. COMMAND BYTE, REGISTER ADDRESS**

A[5:0]	Access	Description	Content
00h	R/W	Control Register CONTROL_0	Device mode control, Bridge outputs control
01h	R/W	Control Register CONTROL_1	High-side outputs control, ECM control (NCV7706 only)
02h	R/W	Control Register CONTROL_2	Bridge outputs recovery control, PWM enable, ECM setup (NCV7706 only)
03h	R/W	Control Register CONTROL_3	High-side outputs recovery control, PWM enable, Current Sense selection
08h	R/W	PWM Control Register PWM_5/6	PWM control register for OUT5/6 (7b control only)
09h	R/W	PWM Control Register PWM_7/8	PWM control register for OUT7/8 (7b control only)
10h	R/RC	Status Register STATUS_0	Bridge outputs Overcurrent diagnosis
11h	R/RC	Status Register STATUS_1	Bridge outputs Underload diagnosis
12h	R/RC	Status Register STATUS_2	HS outputs Overcurrent and Underload diagnosis, Vs Over- and Under-voltage, EC-mirror
13h	R/W	PWM Control Register PWM_5	PWM control register for OUT5 (10b control only)
14h	R/W	PWM Control Register PWM_6	PWM control register for OUT6 (10b control only)
15h	R/W	PWM Control Register PWM_7	PWM control register for OUT7 (10b control only)
16h	R/W	PWM Control Register PWM_8	PWM control register for OUT8 (10b control only)
3Fh	R/W	Configuration Register CONFIG	Mask bits for global fault bits

**Table 5. CHIP ID INFORMATION**

A[5:0]	Access	Description	Content
00h	RDID	ID header	4300h
01h	RDID	Version	0001h (NCV7705, NCV7706) 0004h (NCV7705A)
02h	RDID	Product Code 1	7700h
03h	RDID	Product Code 2	0500h (NCV7705) 0600h (NCV7706)
3Eh	RDID	SPI-Frame ID	0200h



# NCV7705(A), NCV7706

**Table 6. GLOBAL STATUS BYTE CONTENT**

FLT	Global Fault Bit	
0	No fault Condition	Failures of the Global Status Byte, bits [6:0] are always linked to the Global Fault Bit FLT. This bit is generated by an OR combination of all failure bits of the device (RESB inverted). It is reflected via the SO pin while CSB is held low and NO clock signal is present (before first positive edge of SCLK). The flag will remain valid as long as CSB is held low. This operation does not cause the Transmission error Flag in the Global Status Byte to be set. Signals TW and ULD can be masked.
1	Fault Condition	
TF	SPI Transmission Error	
0	0	

# NCV7705(A), NCV7706

## SPI REGISTERS CONTENT

### CONTROL\_0 Register

Address: 00h

Bit	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
Access type	RW	RW	RW	RW	RW	RW	-	-	-	-	RW	RW	-	-	-	RW
Bit name	HS1	LS1	HS2	LS2	HS3	LS3	0	0	0	0	HS4	LS4	0	0	0	MODE
Reset value	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0

	HSx	LSx		Description	Remark
HS/LS Outputs OUT1-4 Driver Control	0	0	default	OUTx High impedance	If a driver is enabled by the control register AND the corresponding PWM enable bit is set in CONTROL_2 register, the output is only activated if PWM1 (PWM2) input signal is high. Since OUT1..OUT4 are half-bridge outputs, activating both HS and LS at the

## NCV7705(A), NCV7706

### CONTROL\_1 Register

Address: 01h

NCV7705:

Bit	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
Access type	RW	RW	RW	RW	RW	RW	RW	RW	RW	RW	RW	RW	RW	RW	RW	-
Bit name	HS5.1	HS5.0	HS6.1	HS6.0	HS7	HS8	HS9	LS ECFB	DAC5	DAC4	DAC3	DAC2	DAC1	DAC0		

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IS3	IS2	IS1	IS0	Description	Remark
0	0	0	0	OUT1	

**Current  
Sensing  
Selection**

# NCV7705(A), NCV7706

## PWM\_7/8 Register

Address: 09h

Bit	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
Access Type	RW	RW	RW	RW	RW	RW	RW	RW	RW	RW	RW	RW	RW	RW	RW	RW
Bit Name	FSEL7	PW7.6	PW7.5	PW7.4	PW7.3	PW7.2	PW7.1	PW7.0	FSEL8	PW8.6	PW8.5	PW8.4	PW8.3	PW8.2	PW8.1	PW8.0

Reset Value

## NCV7705(A), NCV7706

### STATUS\_0 Register

Address: 10h

Bit	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
Access Type	R/RC	R/RC	R/RC	R/RC	R/RC	R/RC	-	-	-	-	R/RC	R/RC	-	-	-	-
Bit Name	OC HS1	OC LS1	OC HS2	OC LS2	OC HS3	OC LS3	0	0	0	0	OC HS4	OC LS4	0	0	0	0
Reset Value	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0

	OCx	Description	Remark
<b>OUT1-4 Overcurrent Detection</b>	0	No overcurrent detected	During an overcurrent event in one of the HS or LS, the belonging overcurrent status bit STATUS_0.OCx is set and the dedicated output is switchedng



## NCV7705(A), NCV7706

### STATUS\_2 Register

Address: 12h

NCV7705:

Bit	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
Access type	R/RC	R/RC	R/RC	R/RC	R/RC	R/RC	R/RC	R/RC	R/RC	R/RC	-	-	R/RC	R/RC	-	-
Bit name	OC HS5	ULD HS5	OC HS6	ULD HS6	OC HS7	ULD HS7	OC HS8	ULD HS8	OC HS9	ULD HS9	0	0	VSUV	VSOV	0	0
Reset value	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0

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## PWM\_5 Register

Address: 13h

Bit	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
Access Type	RW	-	-	-	-	-	RW	RW	RW	RW	RW	RW	RW	RW		

# NCV7705(A), NCV7706

## PWM\_7 Register

Address: 15h

Bit	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
Access Type	RW	-	-	-	-	-	RW	RW	RW	RW	RW	RW	RW	RW	RW	RW

# NCV7705(A), NCV7706

## CONFIG Register

Address: 3Fh

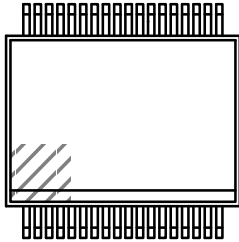
NCV7705:

R15	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
-----	-----	-----	-----	-----	-----	-----	----	----	----	----	----	----	----	----	----	----

**SSOP36 EP**  
**CASE 940AB**  
**ISSUE A**

SCALE 1:1

DATE 19 JAN 2016



DIM	MILLIMETERS	
	MIN	MAX
A		2.65
A1	---	0.10

b	0.18	0.30
c	0.23	0.32

D2		
----	--	--

E2	3.0 <sup>s</sup>	4.10
e	0.50	
h	0.25	0.75
L	0.50	0.10

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